

Silicon PNP Power Transistor

BDW94/A/B/C

DESCRIPTION

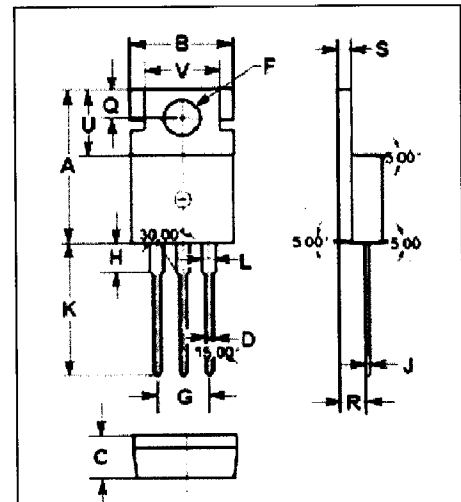
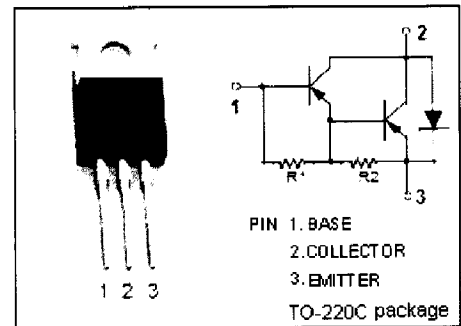
- Collector Current $-I_C = -12A$
- Collector-Emitter Sustaining Voltage-
 : $V_{CEO(SUS)} = -45V(\text{Min})$ - BDW94; $-60V(\text{Min})$ - BDW94A
 $-80V(\text{Min})$ - BDW94B; $-100V(\text{Min})$ - BDW94C
- Complement to Type BDW93/A/B/C

APPLICATIONS

- Designed for hammer drivers, audio amplifier applications.

ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ C$)

SYMBOL	PARAMETER	VALUE	UNIT	
V_{CBO}	Collector-Base Voltage	BDW94	-45	V
		BDW94A	-60	
		BDW94B	-80	
		BDW94C	-100	
V_{CEO}	Collector-Emitter Voltage	BDW94	-45	V
		BDW94A	-60	
		BDW94B	-80	
		BDW94C	-100	
V_{EBO}	Emitter-Base Voltage	-5	V	
I_C	Collector Current-Continuous	-12	A	
I_{CM}	Collector Current-Peak	-15	A	
I_B	Base Current	-0.2	A	
P_C	Collector Power Dissipation @ $T_C=25^\circ C$	80	W	
T_J	Junction Temperature	150	$^\circ C$	
T_{stg}	Storage Temperature Range	-65~150	$^\circ C$	



DIM	mm	
	MIN	MAX
A	15.70	15.90
B	9.90	10.10
C	4.20	4.40
D	0.70	0.90
F	3.40	3.60
G	4.98	5.18
H	2.70	2.90
J	0.44	0.46
K	13.20	13.40
L	1.10	1.30
Q	2.70	2.90
R	2.50	2.70
S	1.29	1.31
U	6.45	6.65
V	8.66	8.86

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R_{th-j-c}	Thermal Resistance, Junction to Case	1.5	$^\circ C/W$



Silicon PNP Power Transistor

BDW94/A/B/C

ELECTRICAL CHARACTERISTICS

$T_c=25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT	
$V_{CE(SUS)}$	Collector-Emitter Sustaining Voltage	BDW94	$I_C = -100\text{mA}; I_B = 0$	-45			V
		BDW94A		-60			
		BDW94B		-80			
		BDW94C		-100			
$V_{CE(sat)-1}$	Collector-Emitter Saturation Voltage	$I_C = -5\text{A}; I_B = -20\text{mA}$			-2.0	V	
$V_{CE(sat)-2}$	Collector-Emitter Saturation Voltage	$I_C = -10\text{A}; I_B = -0.1\text{A}$			-3.0	V	
$V_{BE(sat)-1}$	Base-Emitter Saturation Voltage	$I_C = -5\text{A}; I_B = -20\text{mA}$			-2.5	V	
$V_{BE(sat)-1}$	Base-Emitter Saturation Voltage	$I_C = -10\text{A}; I_B = -0.1\text{A}$			-4.0	V	
I_{CBO}	Collector Cutoff Current	BDW94	$V_{CB} = -45\text{V}; I_E = 0$			-0.1	mA
		BDW94A		$V_{CB} = -60\text{V}; I_E = 0$			
		BDW94B		$V_{CB} = -80\text{V}; I_E = 0$			
		BDW94C		$V_{CB} = -100\text{V}; I_E = 0$			
I_{CEO}	Collector Cutoff Current	BDW94	$V_{CE} = -45\text{V}; I_B = 0$			-1.0	mA
		BDW94A		$V_{CE} = -60\text{V}; I_B = 0$			
		BDW94B		$V_{CE} = -80\text{V}; I_B = 0$			
		BDW94C		$V_{CE} = -100\text{V}; I_B = 0$			
I_{EBO}	Emitter Cutoff Current	$V_{EB} = -5\text{V}; I_C = 0$			-2.0	mA	
h_{FE-1}	DC Current Gain	$I_C = -3\text{A}; V_{CE} = -3\text{V}$	1000				
h_{FE-2}	DC Current Gain	$I_C = -5\text{A}; V_{CE} = -3\text{V}$	750		20000		
h_{FE-3}	DC Current Gain	$I_C = -10\text{A}; V_{CE} = -3\text{V}$	100				
V_{ECF-1}	C-E Diode Forward Voltage	$I_F = -5\text{A}$			-2.0	V	
V_{ECF-2}	C-E Diode Forward Voltage	$I_F = -10\text{A}$			-4.0	V	